imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

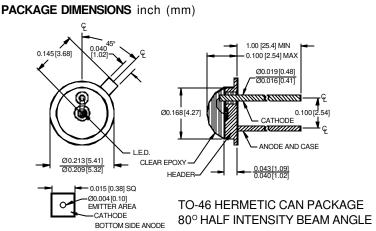
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



PHOTONIC <u>DETECTORS INC.</u>



High-Speed GaAIAs Infrared Point Source Emitter Peak Wavelength 850 nm, Type PDI-E824



FEATURES

- High speed
- High reliablityWide angle
- **DESCRIPTION:** The **PDI-E824** is a GaAlAs, 850 nm, high speed point source emitter. The emitting junction is .004 inch (0.10 mm) diameter. The topside metal cathode forms an optical aperture mask. Pack-

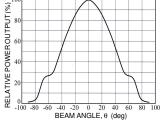
• Wide angle aged in a TO-46 header with a clear epoxy glob top. **ABSOLUTE MAXIMUM RATING** (TA=25°C unless otherwise noted)

				- /				
SYMBOL	PARAMETER	MIN	MAX	UNITS				
Pd	Power Dissipation		200	mW				
l _{EP}	Continuous Forward Current		100	mA				
	Peak Forward Current (10µs, 10Hz)		2.5	А				
V _B	Reverse voltage		2	V				
To & Ts	Storage & Operating Temperature	-55	+125	°C				
TS	Soldering Temperature*		+260	°C				
*1/16 inch from case for 3 secs max								

APPLICATIONS

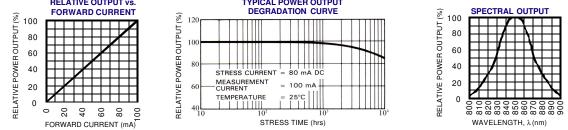
- Fiber optic sources
- Optical encoders
- Point light sources

TYPICAL RADIATION PATTERN



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Po	Output Power	l⊧ = 100 mA	2.5			mW	
VF	Forward Voltage	l⊧ = 100 mA		1.70	2.2	V	
VR	Reverse Breakdown Voltage	l⊧= 10 µµ A	2.0			V	
λP	Peak Wavelength	l⊧ = 20 mA	830	850	870	nm	
Dλ	Spectral Halfwidth	l⊧ = 20 mA		30		nm	
Ct	Terminal Capacitance	V _R = 0 V,f = 1 MHz		60		pF	
tr	Rise Time	l⊧ = 20 mA		15		nS	
tr	Fall Time	l⊧ = 20 mA		15		nS	
RELATIVE OUTPUT vs. TYPICAL POWER OUTPUT							



Information in this technical data she believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. Optical power and radiant intensity measured using uncapped dimpled TO-46 into integrating sphere.